

Title	Investigation on the semiconducting properties of NiO・Cr ₂ O ₃ solid solution
Sub Title	
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Publisher	慶應義塾大学藤原記念工学部
Publication year	1965
Jtitle	Proceedings of the Fujihara Memorial Faculty of Engineering Keio University (慶應義塾大学藤原記念工学部研究報告). Vol.18, No.71 (1965.) ,p.111(47)- 111(47)
JaLC DOI	
Abstract	
Notes	Summaries of Doctor and Master Theses Master of Engineering, 1965 Applied Chemistry
Genre	Departmental Bulletin Paper
URL	https://koara.lib.keio.ac.jp/xoonips/modules/xoonips/detail.php?koara_id=KO50001004-00180071-0047

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Investigation on the Semiconducting Properties of $\text{NiO} \cdot \text{Cr}_2\text{O}_3$ Solid Solution

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Semiconducting properties of $\text{NiO} \cdot \text{Cr}_2\text{O}_3$ and its solid solution were studied. The samples were prepared by solid state reaction of an intimate mixture of purified NiO and Cr_2O_3 powders used as starting material. Chemical analysis, microscopic observation, X-ray analysis and measurement of electrical conductivity and thermoelectromotive force were carried out for these samples.

$\text{NiO} \cdot \text{Cr}_2\text{O}_3$ was found to dissolve nearly 12 mol % of NiO at 1300°C . Mechanism of the dissolutions was seemed to be explained by formation of vacancies in 16 d site up to 6 mol % NiO , and by the replacement of Cr ion with Ni ion from 6 to 12 mol % of NiO .

Cr_2O_3 doesn't dissolve into $\text{NiO} \cdot \text{Cr}_2\text{O}_3$ appreciably up 1300°C , but the solubility reaches to nearly 3 mol % at 1800°C .

Electrical conductivity of the solid solution increases as the content of dissolved NiO increases and this solid solution is a P-type semiconductor.

Jahn-Teller distortion of the solid solution decreases as the content of dissolved NiO increases and tetragonality approaches toward 1.

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